High Performance
128K×8
CMOS SRAM

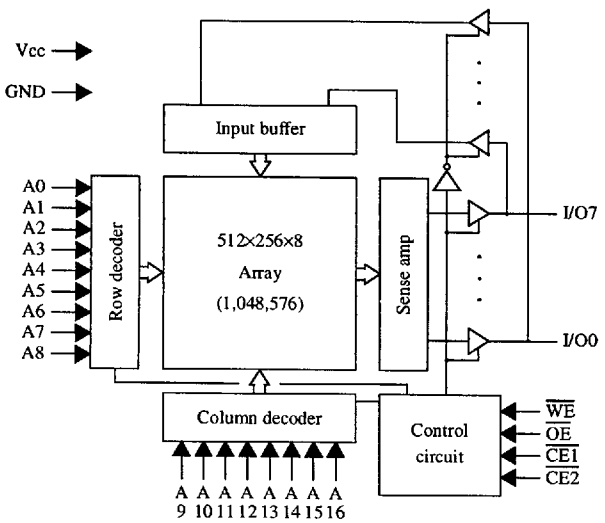
AS7C1024
AS7C1024L

128K×8 CMOS SRAM

Features

- Organization: 131,072 words × 8 bits
- High speed
  - 10/12/15/20/25/35 ns address access time
  - 3/3/4/5/6/8 ns output enable access time
- Low power consumption
  - Active: 770 mW max (10 ns cycle)
  - Standby: 55 mW max, CMOS I/O
    11 mW max, CMOS I/O, L version
  - Very low DC component in active power
- 2.0V data retention (L version)
- Equal access and cycle times
- Easy memory expansion with $\overline{CE1}$, CE2, $\overline{OE}$ inputs
- TTL-compatible, three-state I/O
- 32-pin JEDEC standard packages
  - 300 mil PDIP and SOJ
    Socket compatible with 7C256 and 7C512
  - 400 mil PDIP and SOJ
  - 8 × 20 TSOP
- ESD protection >2000 volts
- Latch-up current > 200 mA

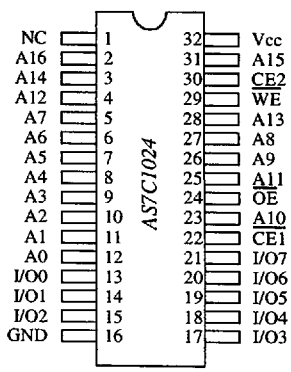
Logic block diagram



Pin arrangement

TSOP 8×20

DIP, SOJ



Selection guide

		7C1024-10	7C1024-12	7C1024-15	7C1024-20	7C1024-25	7C1024-35	Unit
Maximum address access time		10	12	15	20	25	35	ns
Maximum output enable access time		3	3	4	5	6	8	ns
Maximum operating current		140	130	120	110	100	90	mA
Maximum CMOS standby current		10.0	10.0	10.0	10.0	10.0	10.0	mA
	L	2.0	2.0	2.0	2.0	2.0	2.0	mA

Shaded areas contain advance information.

Functional description

The AS7C1024 is a high performance CMOS 1,048,576-bit Static Random Access Memory (SRAM) organized as 131,072 words × 8 bits. It is designed for memory applications where fast data access, low power, and simple interfacing are desired.

Equal address access and cycle times (t_{AA}, t_{RC}, t_{WC}) of 10/12/15/20/25/35 ns with output enable access times (t_{OE}) of 3/3/4/5/6/8 ns are ideal for high performance applications. Active high and low chip enables ($\overline{CE1}$, CE2) permit easy memory expansion with multiple-bank memory systems.

When $\overline{CE1}$ is HIGH or CE2 is LOW the device enters standby mode. The standard AS7C1024 is guaranteed not to exceed 55 mW power consumption in standby mode; the L version is guaranteed not to exceed 11 mW, and typically requires only 5 mW. The L version also offers 2.0V data retention.

A write cycle is accomplished by asserting write enable ($\overline{WE}$) and both chip enables ($\overline{CE1}$, CE2). Data on the input pins I/O0-I/O7 is written on the rising edge of $\overline{WE}$ (write cycle 1) or the active-to-inactive edge of $\overline{CE1}$ or CE2 (write cycle 2). To avoid bus contention, external devices should drive I/O pins only after outputs have been disabled with output enable ($\overline{OE}$) or write enable ($\overline{WE}$).

A read cycle is accomplished by asserting output enable ($\overline{OE}$) and both chip enables ($\overline{CE1}$, CE2), with write enable ($\overline{WE}$) HIGH. The chip drives I/O pins with the data word referenced by the input address. When either chip enable or output enable is inactive, or write enable is active, output drivers stay in high-impedance mode.

All chip inputs and outputs are TTL-compatible, and operation is from a single 5V supply. The AS7C1024 is packaged in common industry standard packages.

Absolute maximum ratings

Parameter	Symbol	Min	Max	Unit
Voltage on any pin relative to GND	V_t	−0.5	+7.0	V
Power dissipation	P_D	–	1.0	W
Storage temperature (plastic)	T_{stg}	−55	+150	°C
Temperature under bias	T_{bias}	−10	+85	°C
DC output current	I_{out}	–	20	mA

Stresses greater than those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Truth table

$\overline{CE1}$	CE2	$\overline{WE}$	$\overline{OE}$	Data	Mode
H	X	X	X	High Z	Standby (I_{SB}, I_{SB1})
X	L	X	X	High Z	Standby (I_{SB}, I_{SB1})
L	H	H	H	High Z	Output disable
L	H	H	L	D_{out}	Read
L	H	L	X	D_{in}	Write

Key: X = Don't Care, L = LOW, H = HIGH

Recommended operating conditions

(T_a = 0°C to +70°C)

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.5	5.0	5.5	V
	GND	0.0	0.0	0.0	V
Input voltage	V_{IH}	2.2	–	V_{CC}+1	V
	V_{IL}	−0.5†	–	0.8	V

†V_{IL} min = −3.0V for pulse width less than $t_{RC}/2$.

DC operating characteristics[1]

(V_{CC} = 5V±10%, GND = 0V, T_a = 0°C to +70°C)

Parameter	Symbol	Test Conditions		-10 Min	-10 Max	-12 Min	-12 Max	-15 Min	-15 Max	-20 Min	-20 Max	-25 Min	-25 Max	-35 Min	-35 Max	Unit
Input leakage current	$\|I_{LI}\|$	V_{CC} = Max, V_{in} = GND to V_{CC}		–	1	–	1	–	1	–	1	–	1	–	1	µA
Output leakage current	$\|I_{LO}\|$	$\overline{CE1}$ = V_{IH} or CE2 = V_{IL}, V_{CC} = Max, V_{out} = GND to V_{CC}		–	1	–	1	–	1	–	1	–	1	–	1	µA
Operating power supply current	I_{CC}	$\overline{CE1}$ = V_{IL}, CE2 = V_{IH}, f = f_{max}, I_{out} = 0 mA		–	140	–	130	–	120	–	110	–	100	–	90	mA
			L	–	135	–	125	–	115	–	105	–	95	–	75	mA
Standby power supply current	I_{SB}	$\overline{CE1}$ = V_{IH} or CE2 = V_{IL}, f = f_{max}		–	55	–	50	–	40	–	40	–	35	–	35	mA
			L	–	50	–	45	–	35	–	35	–	30	–	30	mA
	I_{SB1}	$\overline{CE1}$ ≥ V_{CC}–0.2V or CE2 ≤0.2V, V_{in} ≤ 0.2V or V_{in} ≥ V_{CC}–0.2V, f = 0		–	10	–	10	–	10	–	10	–	10	–	10	mA
			L	–	2.0	–	2.0	–	2.0	–	2.0	–	2.0	–	2.0	mA
Output voltage	V_{OL}	I_{OL} = 8 mA, V_{CC} = Min		–	0.4	–	0.4	–	0.4	–	0.4	–	0.4	–	0.4	V
	V_{OH}	I_{OH} = –4 mA, V_{CC} = Min		2.4	–	2.4	–	2.4	–	2.4	–	2.4	–	2.4	–	V

Shaded areas contain advance information.

Capacitance[2]

(f = 1 MHz, T_a = Room Temperature, V_{CC} = 5V)

Parameter	Symbol	Signals	Test Conditions	Max	Unit
Input capacitance	C_{IN}	A, $\overline{CE1}$, CE2, $\overline{WE}$, $\overline{OE}$	V_{in} = 0V	5	pF
I/O capacitance	$C_{I/O}$	I/O	V_{in} = V_{out} = 0V	7	pF

Read cycle[3,9,12]

(V_{CC} = 5V±10%, GND = 0V, T_a = 0°C to +70°C)

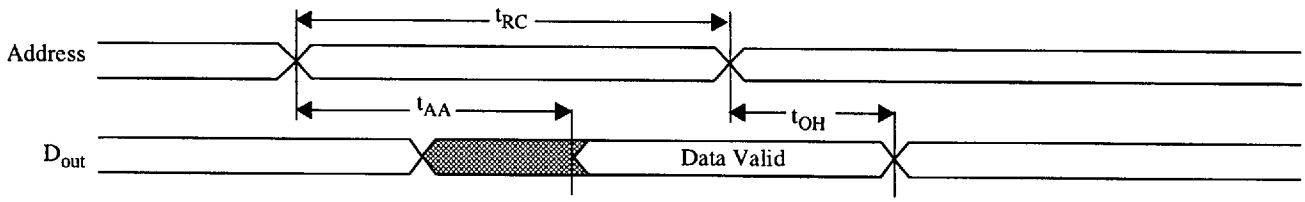
Parameter	Symbol	-10 Min	-10 Max	-12 Min	-12 Max	-15 Min	-15 Max	-20 Min	-20 Max	-25 Min	-25 Max	-35 Min	-35 Max	Unit	Notes
Read cycle time	t_{RC}	10	–	12	–	15	–	20	–	25	–	35	–	ns	
Address access time	t_{AA}	–	10	–	12	–	15	–	20	–	25	–	35	ns	3
Chip enable ($\overline{CE1}$) access time	t_{ACE1}	–	10	–	12	–	15	–	20	–	25	–	35	ns	3, 12
Chip enable (CE2) access time	t_{ACE2}	–	10	–	12	–	15	–	20	–	25	–	35	ns	3, 12
Output enable ($\overline{OE}$) access time	t_{OE}	–	3	–	3	–	4	–	5	–	6	–	8	ns	
Output hold from address change	t_{OH}	2	–	3	–	3	–	3	–	3	–	3	–	ns	5
$\overline{CE1}$ LOW to output in Low Z	t_{CLZ1}	3	–	3	–	3	–	3	–	3	–	3	–	ns	4, 5, 12
CE2 HIGH to output in Low Z	t_{CLZ2}	3	–	3	–	3	–	3	–	3	–	3	–	ns	4, 5, 12
$\overline{CE1}$ HIGH to output in High Z	t_{CHZ1}	–	3	–	3	–	4	–	5	–	6	–	8	ns	4, 5, 12
CE2 LOW to output in High Z	t_{CHZ2}	–	3	–	3	–	4	–	5	–	6	–	8	ns	4, 5, 12
$\overline{OE}$ LOW to output in Low Z	t_{OLZ}	0	–	0	–	0	–	0	–	0	–	0	–	ns	4, 5
$\overline{OE}$ HIGH to output in High Z	t_{OHZ}	–	3	–	3	–	4	–	5	–	6	–	8	ns	4, 5
Power up time	t_{PU}	0	–	0	–	0	–	0	–	0	–	0	–	ns	4, 5, 12
Power down time	t_{PD}	–	10	–	12	–	15	–	20	–	25	–	35	ns	4, 5, 12

Key to switching waveforms

Rising input | Falling input | Undefined output/don't care

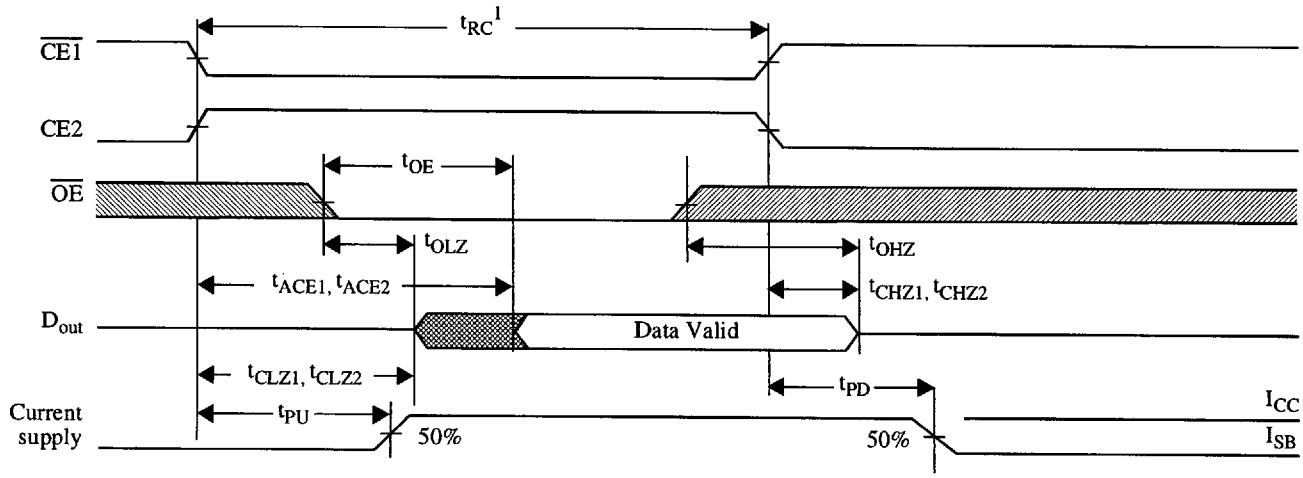
Read waveform 1[3,6,7,9,12]

Address controlled



Read waveform 2[3,6,8,9,12]

$\overline{CE1}$ and CE2 controlled



Write cycle[11, 12]

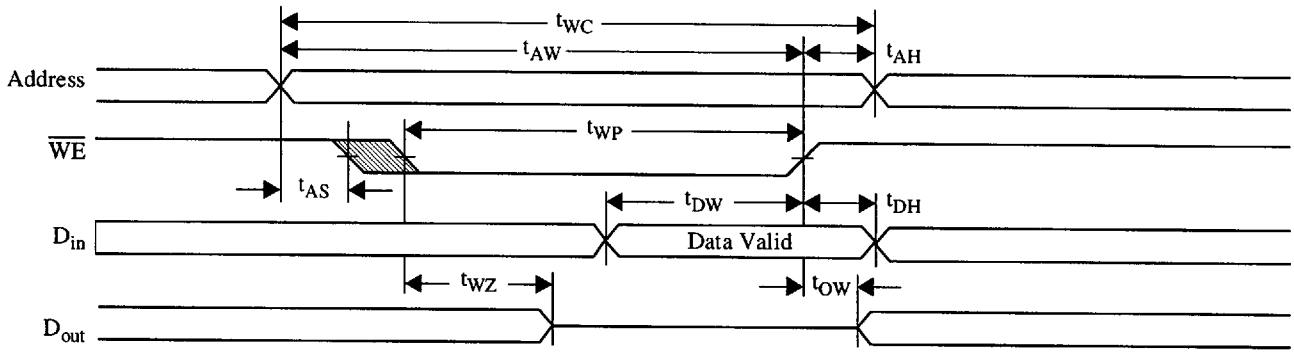
(V_{CC} = 5V±10%, GND = 0V, T_a = 0°C to +70°C)

		-10		-12		-15		-20		-25		-35			
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit	Notes
Write cycle time	t_{WC}	10	–	12	–	15	–	20	–	20	–	30	–	ns	
Chip enable ($\overline{CE1}$) to write end	t_{CW1}	9	–	10	–	12	–	12	–	15	–	20	–	ns	12
Chip enable (CE2) to write end	t_{CW2}	9	–	10	–	12	–	12	–	15	–	20	–	ns	12
Address setup to write end	t_{AW}	9	–	10	–	12	–	12	–	15	–	20	–	ns	
Address setup time	t_{AS}	0	–	0	–	0	–	0	–	0	–	0	–	ns	12
Write pulse width	t_{WP}	7	–	8	–	9	–	12	–	15	–	17	–	ns	
Address hold from end of write	t_{AH}	0	–	0	–	0	–	0	–	0	–	0	–	ns	
Data valid to write end	t_{DW}	6	–	6	–	9	–	10	–	10	–	12	–	ns	
Data hold time	t_{DH}	0	–	0	–	0	–	0	–	0	–	0	–	ns	4, 5
Write enable to output in High Z	t_{WZ}	–	5	–	5	–	5	–	5	–	5	–	5	ns	4, 5
Output active from write end	t_{OW}	3	–	3	–	3	–	3	–	3	–	3	–	ns	4, 5

Shaded areas contain advance information.

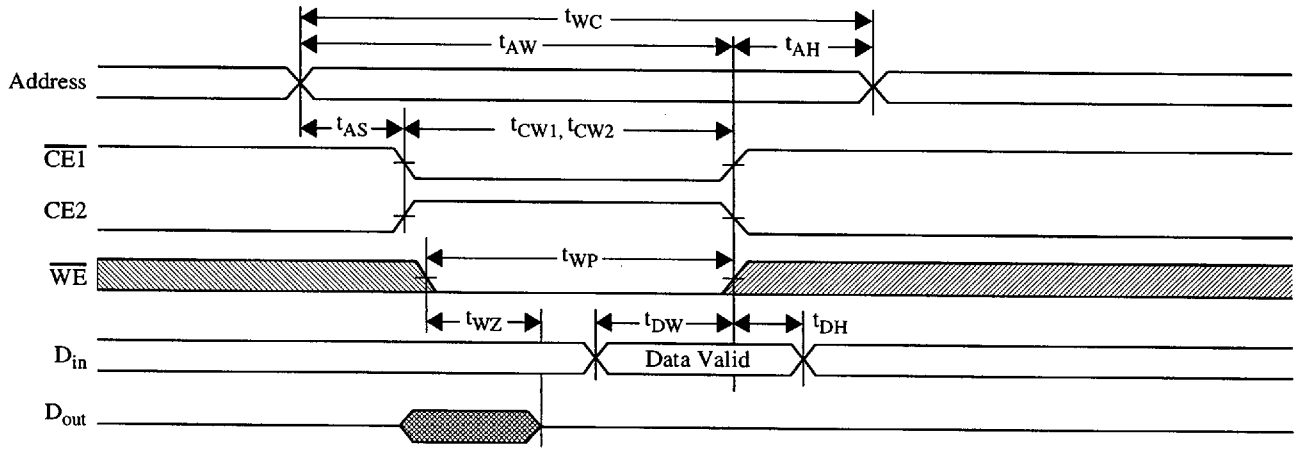
Write waveform 1[10,11,12]

$\overline{WE}$ controlled



Write waveform 2[10,11,12]

$\overline{CE1}$ and CE2 controlled



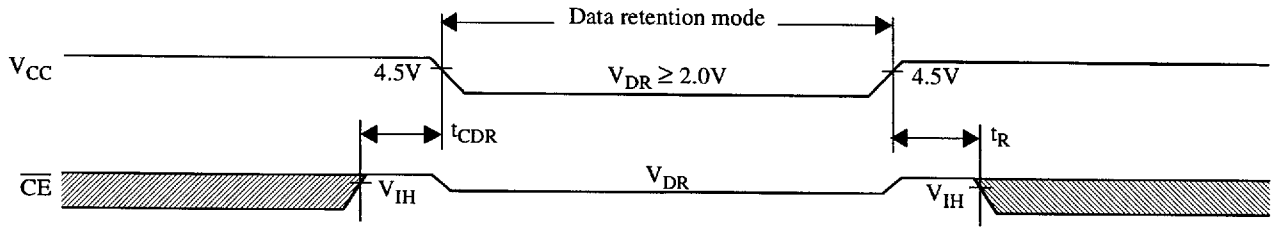
Data retention characteristics

L version only

Parameter	Symbol	Test Conditions	Min	Max	Unit
V_{CC} for data retention	V_{DR}	V_{CC} = 2.0V	2.0	–	V
Data retention current	I_{CCDR}	$\overline{CE1} \geq V_{CC}-0.2V$ or	–	500	µA
Chip deselect to data retention time	t_{CDR}	CE2 ≤ 0.2V	0	–	ns
Operation recovery time	t_R	$V_{in} \geq V_{CC}-0.2V$ or	t_{RC}	–	ns
Input leakage current	$\lvert I_{LI} \rvert$	$V_{in} \leq 0.2V$	–	1	µA

Data retention waveform

L version only



AC test conditions

- Output load: see Figure B, except for t_{CLZ} and t_{CHZ} see Figure C.
- Input pulse level: GND to 3.0V. See Figure A.
- Input rise and fall times: 5 ns. See Figure A.
- Input and output timing reference levels: 1.5V.

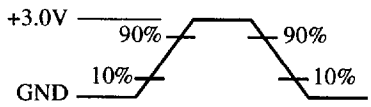


Figure A: Input waveform

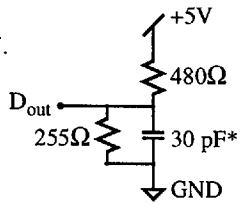


Figure B: Output load

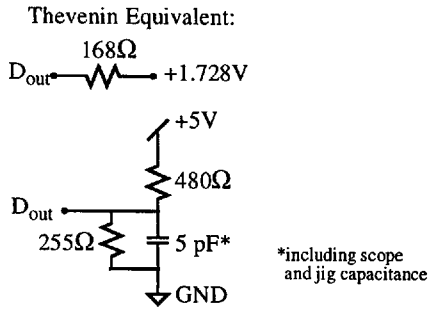


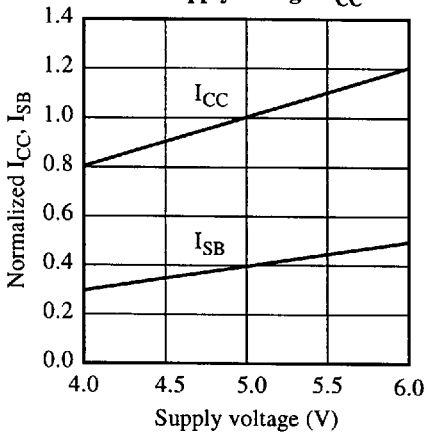
Figure C: Output load for t_{CLZ}, t_{CHZ}

Notes

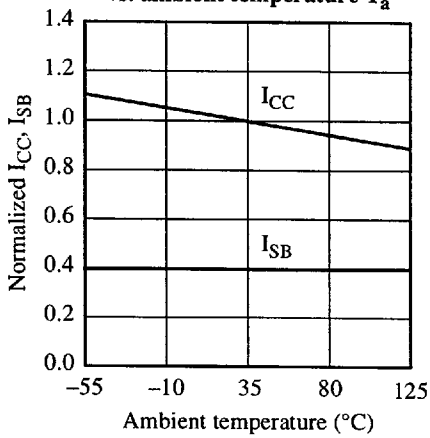
1 During V_{CC} power-up, a pull-up resistor to V_{CC} on $\overline{CE1}$ is required to meet I_{SB} specification.
2 This parameter is sampled and not 100% tested.
3 For test conditions, see *AC Test Conditions*, Figures A, B, C.
4 t_{CLZ} and t_{CHZ} are specified with CL = 5pF as in Figure C. Transition is measured ±500mV from steady-state voltage.
5 This parameter is guaranteed but not tested.
6 $\overline{WE}$ is HIGH for read cycle.
7 $\overline{CE1}$ and $\overline{OE}$ are LOW and CE2 is HIGH for read cycle.
8 Address valid prior to or coincident with $\overline{CE}$ transition LOW.
9 All read cycle timings are referenced from the last valid address to the first transitioning address.
10 $\overline{CE1}$ or $\overline{WE}$ must be HIGH or CE2 LOW during address transitions.
11 All write cycle timings are referenced from the last valid address to the first transitioning address.
12 $\overline{CE1}$ and CE2 have identical timing.

Typical DC and AC characteristics

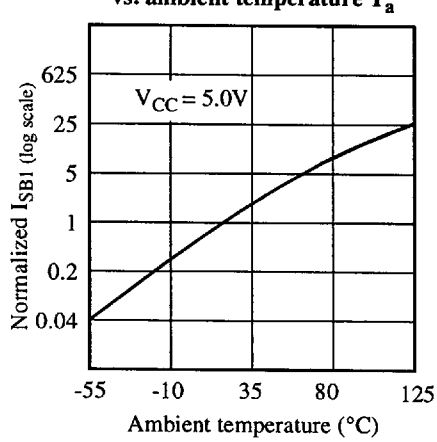
Normalized supply current I_{CC}, I_{SB} vs. supply voltage V_{CC}



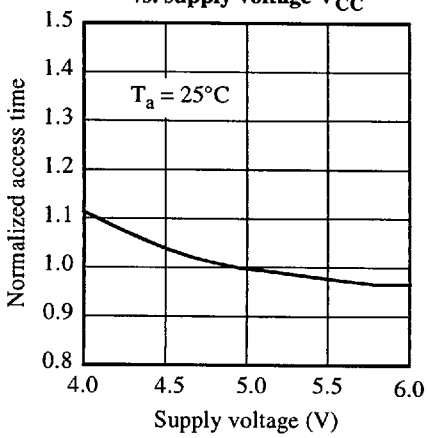
Normalized supply current I_{CC}, I_{SB} vs. ambient temperature T_a



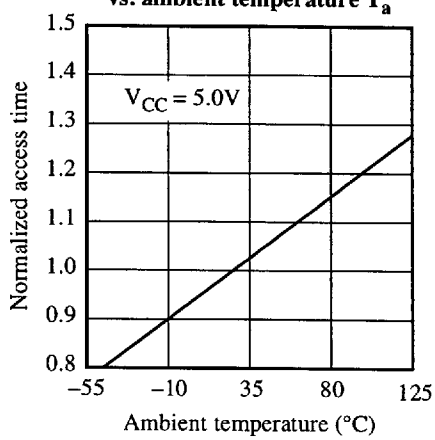
Normalized supply current I_{SB1} vs. ambient temperature T_a



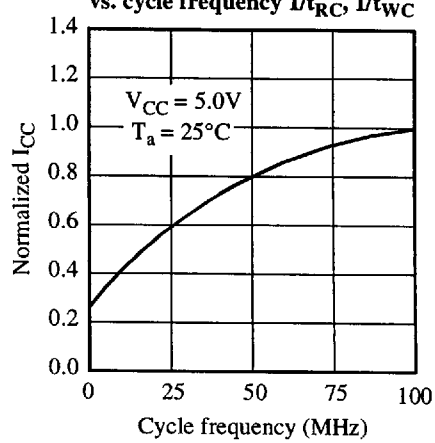
Normalized access time t_{AA} vs. supply voltage V_{CC}



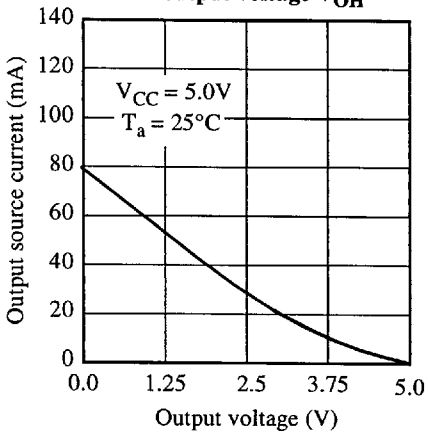
Normalized access time t_{AA} vs. ambient temperature T_a



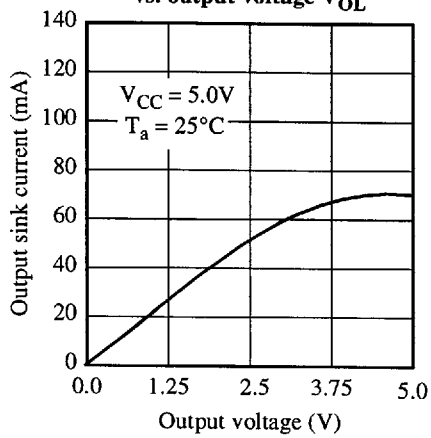
Normalized supply current I_{CC} vs. cycle frequency $1/t_{RC}$, $1/t_{WC}$



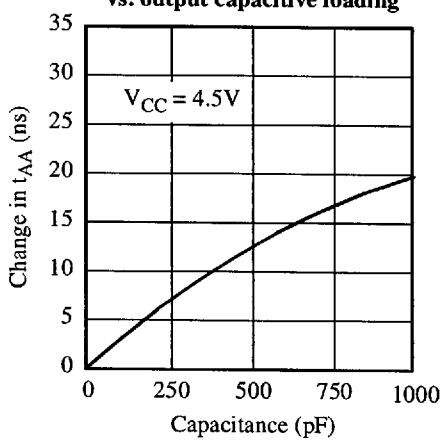
Output source current I_{OH} vs. output voltage V_{OH}



Output sink current I_{OL} vs. output voltage V_{OL}



Typical access time change Δt_{AA} vs. output capacitive loading



Ordering codes

Package \ Access Time	10 ns	12 ns	15 ns	20 ns	25 ns	35 ns
Plastic DIP, 300 mil	AS7C1024-10TPC AS7C1024L-10TPC	AS7C1024-12TPC AS7C1024L-12TPC	AS7C1024-15TPC AS7C1024L-15TPC	AS7C1024-20TPC AS7C1024L-20TPC	AS7C1024-25TPC AS7C1024L-25TPC	AS7C1024-35TPC AS7C1024L-35TPC
Plastic DIP, 400 mil	AS7C1024-10PC AS7C1024L-10PC	AS7C1024-12PC AS7C1024L-12PC	AS7C1024-15PC AS7C1024L-15PC	AS7C1024-20PC AS7C1024L-20PC	AS7C1024-25PC AS7C1024L-25PC	AS7C1024-35PC AS7C1024L-35PC
Plastic SOJ, 300 mil	AS7C1024-10TJC AS7C1024L-10TJC	AS7C1024-12TJC AS7C1024L-12TJC	AS7C1024-15TJC AS7C1024L-15TJC	AS7C1024-20TJC AS7C1024L-20TJC	AS7C1024-25TJC AS7C1024L-25TJC	AS7C1024-35TJC AS7C1024L-35TJC
Plastic SOJ, 400 mil	AS7C1024-10JC AS7C1024L-10JC	AS7C1024-12JC AS7C1024L-12JC	AS7C1024-15JC AS7C1024L-15JC	AS7C1024-20JC AS7C1024L-20JC	AS7C1024-25JC AS7C1024L-25JC	AS7C1024-35JC AS7C1024L-35JC
TSOP 8×20	AS7C1024-10TC AS7C1024L-10TC	AS7C1024-12TC AS7C1024L-12TC	AS7C1024-15TC AS7C1024L-15TC	AS7C1024-20TC AS7C1024L-20TC	AS7C1024-25TC AS7C1024L-25TC	AS7C1024-35TC AS7C1024L-35TC

Shaded areas contain advance information.

Part numbering system

AS7C	1024	X	-XX	X	C
SRAM Prefix	Device Number	Blank = Standard Power L = Low Power	Access Time	Package: P = PDIP 400 mil T = TSOP 8×20 TJ = SOJ 300 mil J = SOJ 400 mil	Commercial Temperature Range, 0°C to 70°C

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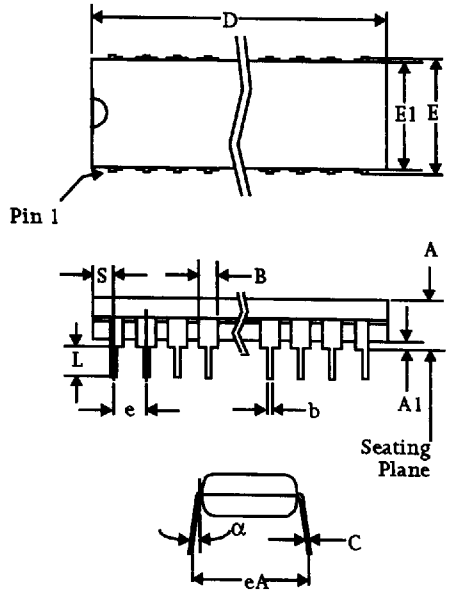
Package diagrams

Plastic dual in-line package (PDIP)

	20-pin 300 mil		28-pin 300 mil		32-pin 300 mil		32-pin 400 mil	
	Min	Max	Min	Max	Min	Max	Min	Max
A	-	0.175	-	0.175	-	0.180	-	0.200
A1	0.010	-	0.010	-	0.015	-	0.015	-
B	0.046	0.054	0.058	0.064	0.045	0.055	0.045	0.065
b	0.018	0.024	0.016	0.022	0.015	0.021	0.014	0.022
C	0.008	0.014	0.008	0.014	0.008	0.012	0.009	0.015
D	-	0.980	-	1.400	-	1.571	-	1.620
E	0.290	0.310	0.295	0.320	0.300	0.325	0.390	0.425
E1	0.263	0.293	0.278	0.298	0.280	0.295	0.340	0.390
e	0.100 BSC		0.100 BSC		0.100 BSC		0.100 BSC	
eA	0.310	0.350	0.330	0.370	0.330	0.370	0.430	0.470
L	0.110	0.130	0.120	0.140	0.110	0.142	0.118	0.162
α	0°	15°	0°	15°	0°	15°	0°	15°
S	-	0.040	-	0.055	-	0.043	-	0.065

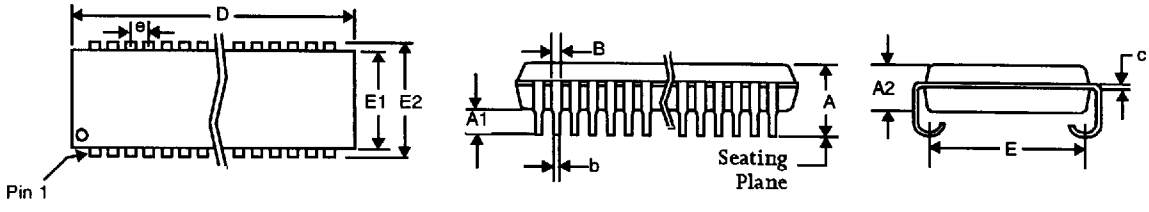
Dimensions in inches



Plastic small outline J-bend (SOJ)

	20/26-pin 300 mil		28-pin 300 mil		32-pin 300 mil		28-pin 400 mil		32-pin 400 mil		36-pin 400 mil		40-pin 400 mil		42-pin 400 mil		44-pin 400 mil	
	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max
A	-	0.140	-	0.140	-	0.145	0.132	0.146	-	0.145	-	-	-	0.145	0.128	0.148	0.128	0.148
A1	0.020	-	0.025	-	0.025	-	0.062	-	0.025	-	-	-	0.025	-	0.025	-	0.025	-
A2	0.095	0.105	0.095	0.105	0.086	0.105	0.105	115	0.086	0.115	0.102 NOM		0.086	0.115	1.105	1.115	1.105	1.115
B	0.025	0.032	0.028 TYP		0.026	0.032	0.024	0.032	0.026	0.032	-	0.032	0.026	0.032	0.026	0.032	0.026	0.032
b	0.016	0.022	0.018 TYP		0.014	0.020	0.013	0.021	0.015	0.020	0.013	0.021	0.015	0.022	0.015	0.020	0.015	0.020
c	0.008	0.014	0.010 TYP		0.006	0.013	0.005	0.012	0.007	0.013	-	-	0.007	0.014	0.007	0.013	0.007	0.013
D	-	0.686	-	0.730	0.820	0.830	0.720	0.729	0.820	0.830	0.920	0.930	1.015	1.035	1.070	1.080	1.120	1.130
E	0.327	0.347	0.327	0.347	0.330	0.340	0.430	0.440	0.435	0.445	0.350	0.390	0.435	0.445	0.370 NOM		0.370 NOM	
E1	0.295	0.305	0.295	0.305	0.292	0.305	0.395	0.405	0.395	0.405	0.400 NOM		0.395	0.405	0.395	0.405	0.395	0.405
E2	0.245	0.285	0.245	0.285	0.250	0.275	0.354	0.378	0.360	0.380	0.435	0.445	0.348	0.390	0.435	0.445	0.435	0.445
e	0.050 BSC		0.050 BSC		0.050 BSC		0.050 BSC		0.050 BSC		0.045	0.055	0.050 BSC		0.050 NOM		0.050 NOM	

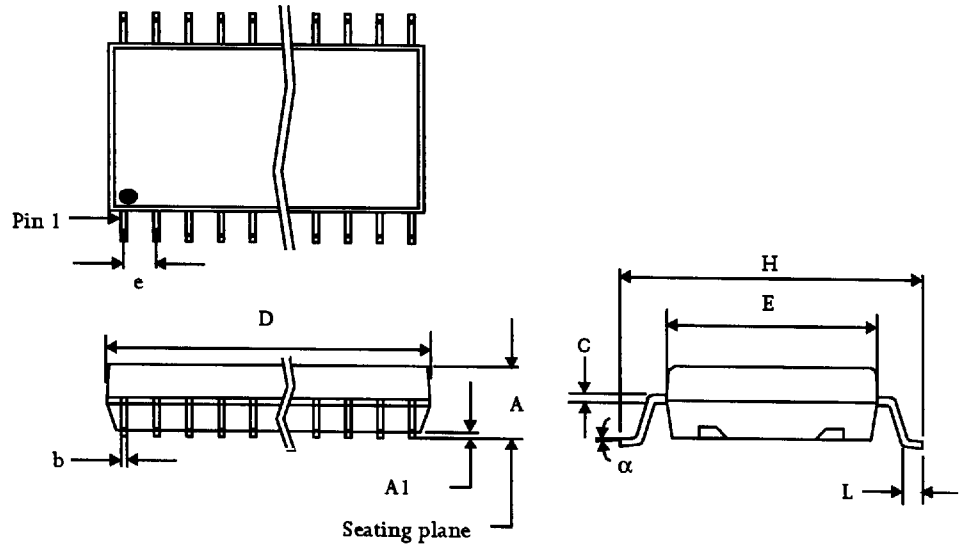
Dimensions in inches



Plastic small outline gull wing IC (SOIC)

	28-pin 330 mil	
	Min	Max
A	-	0.112
A1	0.004	-
b	0.014	0.020
C	0.008	0.014
D	-	0.733
e	0.050 nominal	
E	0.326	0.336
H	0.453	0.477
L	0.028	0.044
α	0°	10°

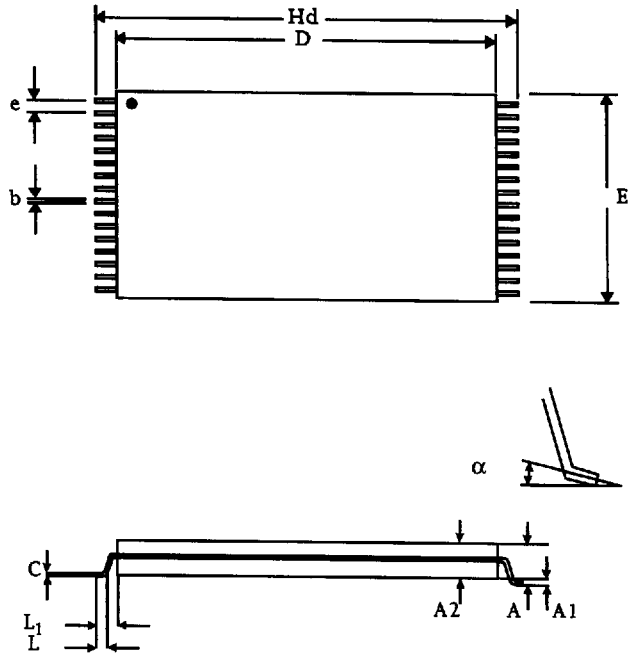
Dimensions in inches

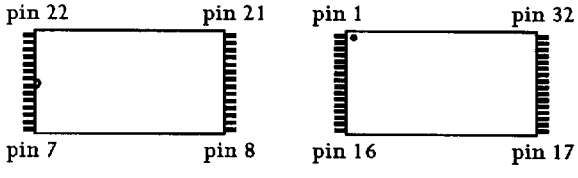


Thin small outline package (TSOP-I)

	28-pin 8×13.4		32-pin 8×20		40-pin 10×20	
	Min	Max	Min	Max	Min	Max
A	-	1.20	-	1.20	-	1.20
A1	0.05	0.15	0.05	0.15	0.05	0.15
A2	0.90	1.05	0.90	1.05	0.95	1.05
b	0.17	0.27	0.17	0.23	0.17	0.27
C	0.10	-	0.10	-	0.10	0.20
D	11.70	11.90	18.20	18.60	18.30	18.50
e	0.55 nominal		0.50 nominal		0.50 nominal	
E	8.0 nominal		7.80	8.20	9.90	10.10
Hd	13.20	13.60	19.80	20.20	19.80	20.20
L	0.30	0.70	0.40	0.60	0.50	0.70
α	0°	5°	1°	5°	0°	5°

Dimensions in millimeters





28-pin 32-pin